



App. No.09/757,583 Docket: 033082.065

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

First Named Inventor: Matsudo

Group Art Unit: 2823

Application No.: 09/757,583

Examiner: Brairton, Scott A

Filing Date: 01/11/2001

For:

ing Date. 01/11/200

METHOD FOR DEPOSITING TUNGSTEN SILICIDE FILM AND METHOD FOR

PREPARING GATE ELECTRODE/WIRING

## AMENDMENT AND RESPONSE TO OFFICE ACTION

Box Amendment Commissioner for Patents Washington, D.C. 20231

A response to the Office Action mailed May 14, 2002 is being timely filed by the August 14, 2002 due date. Applicants request amendment of the application as follows.

## AMENDMENT OF THE CLAIMS

Please add new claims 16-21 as shown by the attached clean version of the new claims. Applicants have enclosed the requisite fees for the additional claims.

## REMARKS

Upon entry of the amendments, claims 1-21 will be pending in the application.

The Examiner has indicated that claims 1-7 are allowable because the prior art of record fails to disclose a method of depositing a tungsten silicide layer using a phosphorous containing gas as claimed by the instant application.

The Examiner has also indicated that claims 9-11, 13, and 14 would be allowable if rewritten in independent form including all the limitations of their base claim and any intervening claim.

08/15/2002 CCHAU1

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